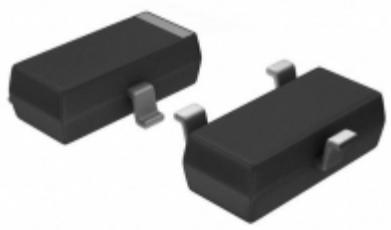

	<h2 style="color: red;">FDN359AN</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FDN359AN</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 2.7A SSOT-3</p> <p><b>Datenblätter:</b> <a href="#">1.FDN359AN.pdf</a> <a href="#">2.FDN359AN.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 149363 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FDN359AN</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 30V 2.7A SSOT-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	149363 pcs Stock
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SuperSOT-3
Verlustleistung (max)	500mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.7A (Ta)
Rds On (Max) @ Id, Vgs	46 mOhm @ 2.7A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	480pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

FDN359AN ist neu im Original, Suche FDN359AN Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDN359AN Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FDN359AN: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FDN359BN</b> Fairchild/ON Semiconductor MOSFET N-CH 30V 2.7A 3SSOT	 <b>FDN359BN</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 2.7A SSOT3	 <b>FDN359BN</b> FDK America MOSFET N-CH 30V 2.7A 3SSOT	 <b>FDN358P_NL</b> FAIRCHILD FAIRCHILD SOT23-3
 <b>FDN358P</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 1.5A SSOT3	 <b>FDN358P</b> Fairchild/ON Semiconductor MOSFET P-CH 30V 1.5A SSOT3	 <b>FDN358</b> FAIRCHILD FDN358 FAIRCHILD	 <b>FDN358P-NL</b> FAIRCHI FDN358P-NL FAIRCHI

### heiße Teile

Mehr

<a href="#">FDN336P-NL</a>	<a href="#">FDN336P_NL</a>	<a href="#">FDN337N-NL</a>	<a href="#">FDN337N-NL/337</a>	<a href="#">FDN338P-NL</a>
<a href="#">FDN338P-NL/338</a>	<a href="#">FDN339AN</a>	<a href="#">FDN339AN</a>	<a href="#">FDN339AN-NL</a>	<a href="#">FDN339N-NL</a>
<a href="#">FDN340P-NL</a>	<a href="#">FDN342P-NL</a>	<a href="#">FDN352AP</a>	<a href="#">FDN352AP</a>	<a href="#">FDN352AP-NL</a>
<a href="#">FDN352P-NL</a>	<a href="#">FDN355A-NL</a>	<a href="#">FDN355N-NL</a>	<a href="#">FDN356AP-NL</a>	<a href="#">FDN356P-NL</a>
<a href="#">FDN357N-NL</a>	<a href="#">FDN357NNL</a>	<a href="#">FDN357P-NL</a>	<a href="#">FDN358P-NL</a>	<a href="#">FDN359AN</a>
<a href="#">FDN359AN-NL</a>	<a href="#">FDN359BN</a>	<a href="#">FDN359BN</a>	<a href="#">FDN359BN</a>	<a href="#">FDN359BN-NL</a>
<a href="#">FDN359N-NL</a>	<a href="#">FDN360P-NL</a>	<a href="#">FDN360P-NL/360</a>	<a href="#">FDN361AN</a>	<a href="#">FDN361AN</a>
<a href="#">FDN361AN-NL</a>	<a href="#">FDN361BN</a>	<a href="#">FDN361BN</a>	<a href="#">FDN361BN-NL</a>	<a href="#">FDN362AN-NL</a>
<a href="#">FDN363N-NL</a>	<a href="#">FDN371N-NL</a>	<a href="#">FDN372S-NL</a>	<a href="#">FDN5330SX</a>	<a href="#">FDN537N-NL</a>
<a href="#">FDN5618P</a>	<a href="#">FDN5618P</a>	<a href="#">FDN5618P-NL</a>	<a href="#">FDN5630-NL</a>	<a href="#">FDN5630N-NL</a>

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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